Onsemi

FFSH2065ADN-F155

Description

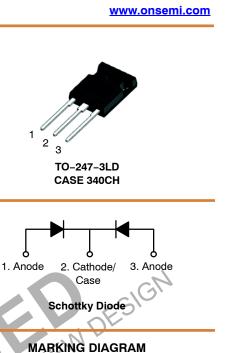
Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching charactristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 64 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
 This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant
 Applications

 General Purpose
 SMPS, Solar Inverter, UPS
 Power Switching Circuits

 A YWW KK FFSH2065



А	= Assembly Plant Code
YWW	= Date Code (Year & Week)
KK	= Lot Traceability Code
FFSH2065ADN	= Specific Device Code

AYWWKK FFSH 2065ADN

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSH2065ADN-F155

Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage	epetitive Reverse Voltage		V
E _{AS}	Single Pulse Avalanche Energy	Pulse Avalanche Energy (Note 1)		mJ
١ _F	Continuous Rectified Forward Current @ T _C < 7	10*/20**	А	
	Continuous Rectified Forward Current @ $T_C < T_C$	Continuous Rectified Forward Current @ T _C < 135°C		
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 25°C, 10 μs	620	А
		T _C = 150°C, 10 μs	580	А
I _{F,SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	56	А
I _{F,RM}	Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	38	А
Ptot	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	93	W
		T _C = 150°C	16	W
T _J , T _{STG}	STG Operating and Storage Temperature Range		-55 to +175	J°C
	TO247 Mounting Torque, M3 Screw		60	> Ncm

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E_{AS} of 64 mJ is based on starting $T_J = 25^{\circ}C$, L = 0.5 mH, I_{AS} = 16 A, V = 50 V.

THERMAL CHARACTERISTICS

THERMAL C			
Symbol	Parameter	alue Unit	
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max 1.61	1*/0.7** °C/W	
NOTE: * Per Leg, ** Per Device			

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V _F	Forward Voltage	$I_{\rm F} = 10$ A, $T_{\rm C} = 25^{\circ}$ C	0'-	1.5	1.75	V
		F = 10 A, T _C = 125°C	-	1.6	2.0	
		I _F = 10 Α, Τ _C = 175°C	-	1.72	2.4	
I _R	Reverse Current	V _R = 650 V, T _C = 25°C	-	-	200	μΑ
	I CE LE	V _R = 650 V, T _C = 125°C	-	-	400	
	DEN. FIR	V _R = 650 V, T _C = 175°C	-	-	600	
Q _C	Total Capacitive Charge	V = 400 V	-	34	-	nC
c	Total Capacitance	V _R = 1 V, f = 100 kHz	-	575	-	pF
		V _R = 200 V, f = 100 kHz	-	62	-	
		V _R = 400 V, f = 100 kHz	-	47	_	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping
FFSH2065ADN-F155	FFSH2065ADN	TO-247-3LD	30 Units

FFSH2065ADN-F155

TYPICAL CHARACTERISTICS

 $(T_J = 25^{\circ}C \text{ UNLESS OTHERWISE NOTED})$

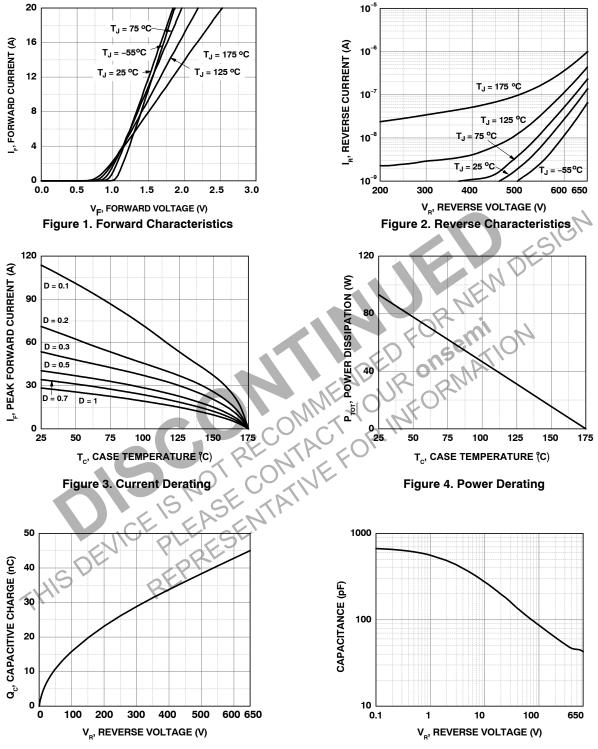




Figure 6. Capacitance vs. Reverse Voltage

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TYPICAL CHARACTERISTICS

(T_J = 25°C UNLESS OTHERWISE NOTED)

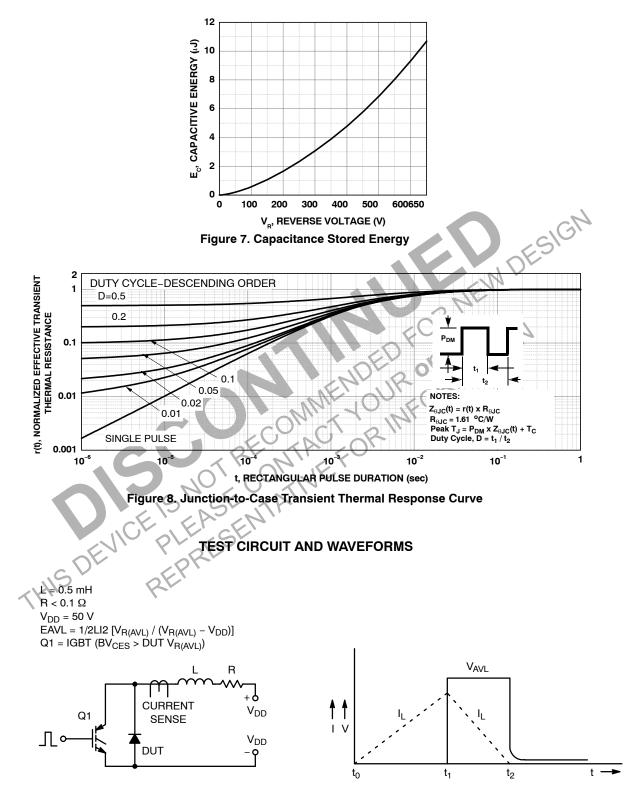
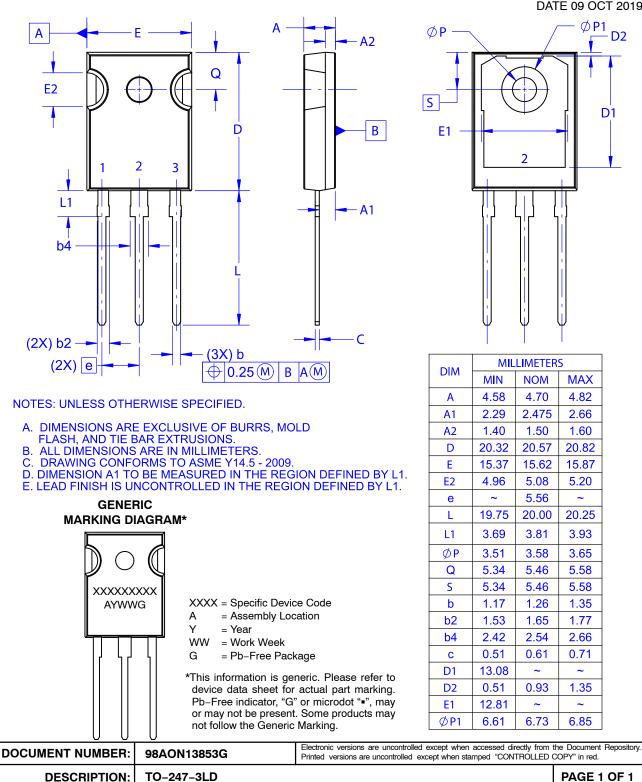


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform



TO-247-3LD CASE 340CH **ISSUE A**

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